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Sheet 1 of 1

PTO 1449  37 CFR 1.501 INFORMATION DISCLOSURE STATEMENT IN A PATENT (use several sheets if necessary)					Docket No. <b>P97,0027</b>		Serial No. <b>08/818,239</b>	
					Applicant <b>Hiroshi Tayanaka</b>			
					Filing Date <b>March 14, 1997</b>		Group Art Unit <b>2813</b>	
<b>U.S. PATENT DOCUMENTS</b>								
Examiner's Initials		Document Number	Date	Name	Class	Subclass	Filing Date If appropriate	
	AA							
	AB							
	AC							
	AD							
<b>FOREIGN PATENT DOCUMENTS</b>								
		Document Number	Date	Country	Class	Subclass	Translation Yes No	
KC	AE	EP 0 554 795 A1	Aug. 11, 1993	EPO	-	-	X	
KC	AF	EP 0 793 263 A2	Sept. 3, 1997	EPO	-	-	X	
	AG							
	AH							
	AI							
	AJ							
	AK							
<b>OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)</b>								
KC	AL	Patent Abstracts of Japan, Vol. 010, No. 039 (E-381), 15 February 1986 & JP 60 196955 A (TOKO INC), 5 October 1985						
KC	AM	T. Yasumatsu, et al., "Ultrathin Si films grown epitaxially on porous silicon", Applied Surface Science, Vol. 48/49, May 1991, pages 414-418, XP-002093161						
KC	AN	M. Ohnishi, et al., "NEW TYPE STRUCTURES OF A-SI SOLAR CELL SUBMODULES FABRICATED BY MICROSCOPIC HOLE SPACING TECHNIQUE", RECORD OF THE PHOTOVOLTAIC SPECIALISTS CONFERENCE, KISSIMIMEE, May 21 - 25, 1990, Vol. 2, No. CONF. 21, 21 May 1990, pages 1394-1399, XP 000480389, INSTITUTE OF ELECTRICAL AND ELECTRONICS ENGINEERS						
KC	AO	Patent Abstracts of Japan, Vol. 018, No. 066 (E-1501), 3 February 1994, & JP 05 283722 A (CANON INC), 29 October 1993						
Examiner		K. [Signature]		Date Considered 9/2/99				
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